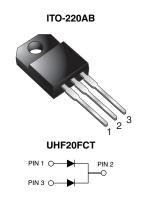


Vishay General Semiconductor

# **Dual Common-Cathode Ultrafast Recovery Rectifier**



PRIMARY CHARACTERISTICS					
I <sub>F(peak)</sub>	10 A x 2				
V <sub>RRM</sub>	300 V				
I <sub>FSM</sub>	180 A				
t <sub>rr</sub>	25 ns				
V <sub>F</sub> at I <sub>F</sub> = 10 A	0.85 V				
T <sub>J</sub> max.	175 °C				

#### **FEATURES**





- Ultrafast recovery times
- · Soft recovery characteristics
- · Low switching losses, high efficiency



COMPLIANT

- High forward surge capability
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### TYPICAL APPLICATIONS

For use in high frequency power factor correctors, switching mode power supplies, freewheeling diodes and secondary dc-to-dc rectification application.

### **MECHANICAL DATA**

Case: ITO-220AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test **Polarity:** As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	UHF20FCT	UNIT		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	300	V		
Maximum DC working forward current at $T_C = 125~^{\circ}C$	per device per diode	I <sub>F(peak)</sub>	20 10	А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	per diode	I <sub>FSM</sub>	180	А		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500	V		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 175	°C		

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	$I_F = 5.0 \text{ A}$ $I_F = 10.0 \text{ A}$	T <sub>A</sub> = 25 °C	$V_{F}$	0.96 1.02	- 1.20	V
	$I_F = 5.0 \text{ A}$ $I_F = 10.0 \text{ A}$	T <sub>A</sub> = 125 °C		0.77 0.85	1 1	
Maximum reverse current per diode (2)	V <sub>R</sub> = 300 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	0.06 25	5 150	μΑ

## **UHF20FCT**

# Vishay General Semiconductor



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$	t <sub>rr</sub>	20	25	ns	
Maximum reverse recovery time per diode	$I_F = 1.0 \text{ A, dI/dt} = 50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } I_{rr} = 0.1 I_{RM}$	t <sub>rr</sub>	28	35	ns	
Typical softness factor (tb/ta)	I <sub>F</sub> = 10 A, dl/dt = 200 A/μs,	S	0.36	=	-	
Typical reverse recovery current	V <sub>R</sub> = 200 V, T <sub>J</sub> = 125 °C	I <sub>RM</sub>	7.0	=	Α	
Typical stored charge	per diode	$Q_{rr}$	160	-	nC	
Typical forward recovery time per diode	$I_F = 10 \text{ A}, \text{ dI/dt} = 80 \text{ A/}\mu\text{s},$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$	t <sub>fr</sub>	150	-	ns	

#### Notes:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL UHF20FCT			
Typical thermal resistance per diode	$R_{\theta JA}^{(1)}$ $R_{\theta JC}^{(2)}$	50 4.6	°C/W	

#### Notes:

- (1) Without heatsink, free air
- (2) With infinite heatsink

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	UHF20FCT-E3/4W	1.74	4W	50/tube	Tube		

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

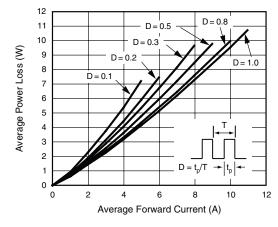


Figure 1. Forward Power Loss Characteristics Per Diode

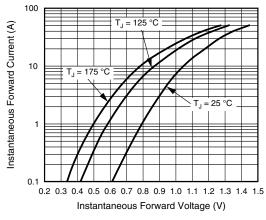


Figure 2. Typical Instantaneous Forward Characteristics Per Diode



## Vishay General Semiconductor

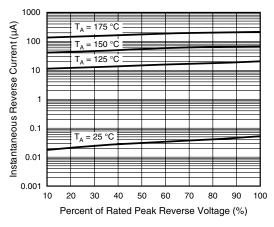


Figure 3. Typical Reverse Leakage Characteristics Per Diode

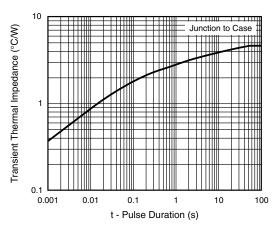


Figure 5. Typical Transient Thermal Impedance Per Diode

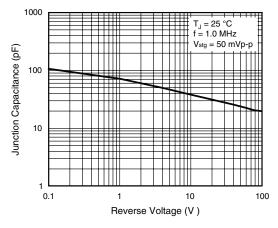
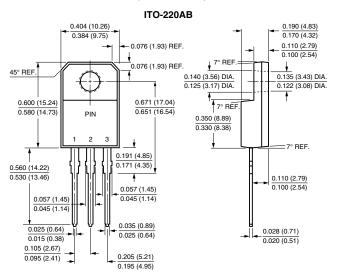


Figure 4. Typical Junction Capacitance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)







Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com Revision: 11-Mar-11